Sanitized Copy Approved for Release 2011/08/08 : CIA-RDP78-03300A001100040001-3	25X1
CONFIDENTIAL	
1961	25X1
MEMORANDUM FOR: THE RECORD	
SUBJECT : Trip Report	
TIME & PLACE : 19-21 June 1961, , New York	25 X 1
ATTENDANCE :	25X1
1. The main purpose of this visit was to return and re-test previously received wire analyzers under contract number 237-1316-0. A secondary purpose was to familiarize with the contractor's test procedures.	25 X 1
2. The undersigned arrived in New York with the twelve (12) rejected analyzers on 19 June 1961.	
3. The undersigned and personnel re-tested the units on 20 June 1961 and conducted repairs where necessary. Attachment #1 describes the nature of the defects and repairs.	25X1
4. It will be noted that practically all defects were the result of defective components. It was felt that defective components would be detected by the 100-Hour "burn-in" before test and shipment from the contractor. This, obviously, is not the case, since a few additional hours are resulting in numerous defective components.	
5. The "burn-in" time on all remaining production units has been doubled to 200 Hours.	
6. On 21 June 1961 the undersigned and rechecked the returned twelve (12) units plus eleven (11) new units. Two of the new units exhibited the noisy transistor problem encountered on the rejects. (These new units had already received twenty (20) additional hours of "life" test.) All new units tested will be retained at the contractor's facility for an additional week of "life" tests.	25X1
7. The twelve (12) re-tested units were returned to Washington on the night of 21 June 1961. paper work concerning accounts.	25 X 1
paper work concerning acceptance and disposition.	25 X 1
Distribution: Orig 1-P-227; 1- ; 1- travel folder; 1-chrono	
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SECRE

ATTACHMENT #1

						
	SEI	RIAL NUMBER		SYMPTOM	DEFECT	REPAIR
		235		Low Audio Amp. Gain	Faulty Transistor	Replace Transistor
SESHET.		238		Erratic Switch	No fault cou	ld be located.
		241		Low Oscillator Output	Faulty Transistor	Replace Transistor
	$ \leq $	244		Inoperative Oscillator	Faulty Transistor	Replace Transistor
	Z	246		Improper Charging Rate	Leaky Battery	Replace Battery
	CONFIDENTIAL	251		Steady VM Reading	Noisy Transistor	Replace Transistor
		252		Steady VM Reading	Noisy Transistor	Replace Transistor
		258		Steady VM Reading	Noisy Transistor	Replace Transistor
		264	a. b.	Erratic Oscillator Steady Voltmeter Reading	Faulty Transistor Noisy Transistor	Replace Transistor
		265		Inoperative Voltmeter on + DC/AUDIO	Faulty Rectifier	Replace Rectifier
		266		Steady VM Reading	Noisy Transistor	Replace Transistor
		267		Steady VM Reading	Noisy Transistor	Replace Transistor

